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Rohm Semiconductor RTQ035P02TR

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RTQ035P02

#### **Transistor**

# DC-DC Converter (-20V, -3.5A) RTQ035P02

#### Features

- 1) Low On-resistance.( $80m\Omega$  at 2.5V)
- 2) High Power Package.
- 3) High speed switching.
- 4) Low voltage drive.(2.5V)

# Applications

DC-DC converter

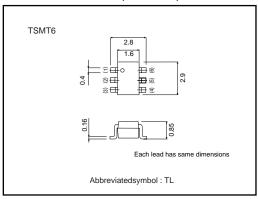
#### Structure

Silicon P-channel **MOSFET** 

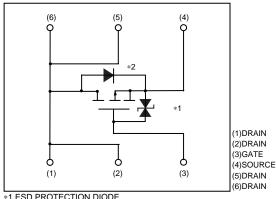
#### Packaging specifications

	Package	Taping		
Туре	Code	TR		
	Basic ordering unit (pieces)	3000		
RTQ035P02	0			

#### ●External dimensions (Units : mm)



#### ●Equivalent circuit



- \*1 ESD PROTECTION DIODE
- \*2 BODY DIODE



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# ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Drain-source voltage		Voss	-20	V	
Gate-source voltage		Vgss	±12	V	
Droin autrant	Continuous	ΙD	±3.5	А	
Drain current	Pulsed	IDP	±17.5	A *1	
Source current	Continuous	Is	-1	А	
(Body diode)	Pulsed	Isp	-4	A *1	
Total power dissipation		Po	1.25	W*2	
Channel temperature		Tch	150	°C	
Range of Storage temperature		Tstg	<b>−55~+150</b>	°C	

<sup>\*1</sup> Pw≦10μs, Duty cycle≦1%

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Gate-source leakage	Igss	-	-	±10	μΑ	Vgs=±12V, Vds=0V	
Drain-source breakdown voltage	V(BR)DSS	-20	-	_	V	ID=-1mA, VGS=0V	
Zero gate voltage drain current	IDSS	_	-	-1	μΑ	Vps=-20V, Vgs=0V	
Gate threshold voltage	VGS(th)	-0.7	-	-2.0	V	VDS=-10V, ID=-1mA	
	RDS(on)	_	50	65	mΩ	In=-3.5A, Vgs=-4.5V	
Static drain-source on-state resistance		_	55	70	mΩ	ID=-3.5A, VGS=-4V	
		_	80	100	mΩ	ID=-1.75A, VGS=-2.5V	
Foward transfer admittance	Y <sub>fs</sub>  *	3.5	-	_	S	Vps=-10V, Ip=-3.5A	
Input capacitance	Ciss	_	1200	_	pF		
Output capacitance	Coss	_	200	_	pF	VDS=-10V,VGS=0V f=1MHz	
Reverse transfer capacitance	Crss	_	130	_	pF	1 - 111112	
Turn-on delay time	td(on) *	_	16	_	ns	ID=-2A VDD = -15V VGS=-4.5V RL=7.5Ω RGS=10Ω	
Rise time	tr *	_	40	_	ns		
Turn-off delay time	td(off) *	_	55	_	ns		
Fall time	t <sub>f</sub> *	_	30	-	ns		
Total gate charge	Qg	_	10.5	_	nC	V <sub>DD</sub> ≒−15V V <sub>GS</sub> =−4.5V I <sub>D</sub> =−3.5A	
Gate-source charge	Qgs	_	2.0	_	nC		
Gate-drain charge	Qgd	_	3.5	_	nC		

	•			,			
Forward voltage		VSD	-	-	-1.2	V	Is=-1A, Vgs=0V



<sup>\*2</sup> Mounted on a ceramic board

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#### **Transistor**

#### Electrical characteristic curves

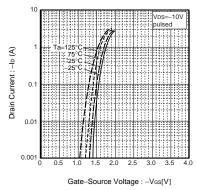
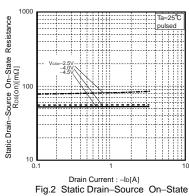


Fig.1 Typical Transfer Characteristics



Resistance vs. Drain Current

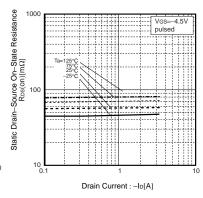


Fig.3 Static Drain-Source On-State Resistance vs.Drain Current

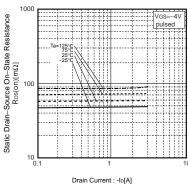


Fig.4 Static Drain-Source On-State Resistancevs.Drain-Current

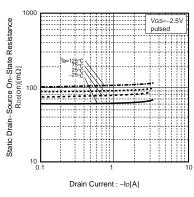


Fig.5 Static Drain-Source On-State Resistance vs. Drain-Current

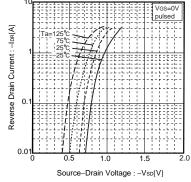


Fig.6 Reverse Drain Current vs. Source-Drain Voltage

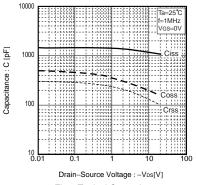


Fig.7 Typical Capactitance vs.Drain-Source Voltage

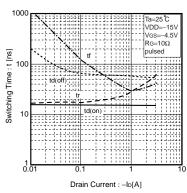


Fig.8 Switching Characteristics

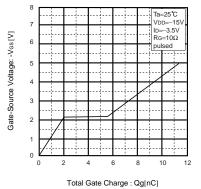


Fig.9 Dynamic Input Characteristics



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#### Measurement circuits

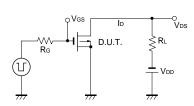


Fig.10 Switching Time Measurement Circuit

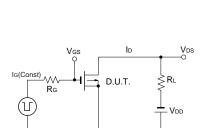


Fig.12 Gate Charge Measurement Circuit

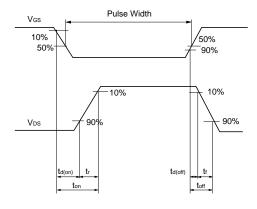


Fig.11 Switching Waveforms

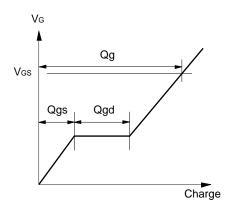


Fig.13 Gate Charge Waveforms



# Distributor of Rohm Semiconductor: Excellent Integrated System Limited

Datasheet of RTQ035P02TR - MOSFET P-CH 20V 3.5A TSMT6

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# Appendix

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